

MC100LVEL90

-3.3 V / -5 V Triple ECL Input to LVPECL Output Translator

Description

The MC100LVEL90 is a triple ECL to LVPECL translator. The device receives either -3.3 V or -5 V differential ECL signals, determined by the V_{EE} supply level, and translates them to +3.3 V differential LVPECL output signals.

To accomplish the level translation, the LVEL90 requires three power rails. The V_{CC} supply should be connected to the positive supply, and the V_{EE} pin should be connected to the negative power supply. The GND pins, as expected, are connected to the system ground plane. Both V_{EE} and V_{CC} should be bypassed to ground via 0.01 μ F capacitors.

Under open input conditions, the \bar{D} input will be biased at $V_{EE}/2$ and the D input will be pulled to V_{EE} . This condition will force the Q output to a LOW, ensuring stability.

The V_{BB} pin, an internally generated voltage supply, is available to this device only. For single-ended input conditions, the unused differential input is connected to V_{BB} as a switching reference voltage. V_{BB} may also rebias AC coupled inputs. When used, decouple V_{BB} and V_{CC} via a 0.01 μ F capacitor and limit current sourcing or sinking to 0.5 mA. When not used, V_{BB} should be left open.

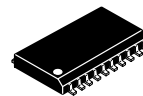
Features

- 500 ps Propagation Delays
- ESD Protection: > 2 kV HBM, > 200 V MM
- The 100 Series Contains Temperature Compensation
- Operating Range: $V_{CC} = 3.0$ V to 3.8 V;
 $V_{EE} = -3.0$ V to -5.5 V; GND = 0 V
- Internal Input Pulldown Resistors
- Q Output will Default LOW with Inputs Open or at V_{EE}
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity: Level 3 (Pb-Free)
For Additional Information, see Application Note [AND8003/D](#)
- Flammability Rating: UL 94 V-0 @ 0.125 in,
Oxygen Index: 28 to 34
- Transistor Count = 261 devices
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant



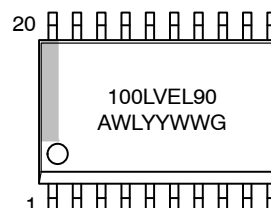
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SOIC-20 WB
DW SUFFIX
CASE 751D

MARKING DIAGRAM*



A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week
G = Pb-Free Package

*For additional marking information, refer to Application Note [AND8002/D](#).

ORDERING INFORMATION

Device	Package	Shipping†
MC100LVEL90DWG	SOIC-20 WB (Pb-Free)	38 Units/Tube
MC100LVEL90DWR2G	SOIC-20 WB (Pb-Free)	1000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

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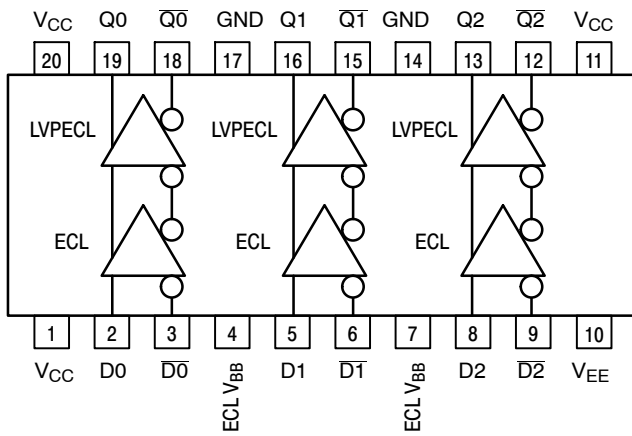


Table 1. PIN DESCRIPTION

PIN	FUNCTION
D _n , \overline{D}_n	ECL Inputs
Q _n , \overline{Q}_n	LVPECL Outputs
ECL V _{BB}	ECL Reference Voltage Output
V _{CC}	Positive Supply
V _{EE}	Negative Supply
GND	Ground

* All V_{CC} pins are tied together on the die.

Warning: All V_{CC}, V_{EE}, and GND pins must be externally connected to Power Supply to guarantee proper operation.

Figure 1. Logic Diagram and Pinout: 20-Lead SOIC (Top View)

Table 2. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V _{CC}	PECL Power Supply	GND = 0 V		8 to 0	V
V _{EE}	NECL Power Supply	GND = 0 V		-8 to 0	V
V _I	NECL Mode Input Voltage	GND = 0 V	V _I ≥ V _{EE}	-6 to 0	V
I _{out}	Output Current	Continuous Surge		50 100	mA
I _{BB}	ECL V _{BB} Sink/Source			± 0.5	mA
T _A	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ _{JA}	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	SOIC-20 WB	90 60	°C/W
θ _{JC}	Thermal Resistance (Junction-to-Case)	Standard Board	SOIC-20 WB	30 to 35	°C/W
T _{sol}	Wave Solder			265	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

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Table 3. NECL INPUT DC CHARACTERISTICS ($V_{CC}= 3.3\text{ V}$; $V_{EE}= -3.3\text{ V}$; $GND= 0\text{ V}$ (Note 1))

Symbol	Characteristic	-40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	V_{EE} Power Supply Current			8.0		6.0	8.0			8.0	mA
V_{IH}	Input HIGH Voltage (Single-Ended)	-1165		-880	-1165		-880	-1165		-880	mV
V_{IL}	Input LOW Voltage (Single-Ended)	-1810		-1475	-1810		-1475	-1810		-1475	mV
ECL V_{BB}	Output Voltage Reference	-1.38		-1.26	-1.38		-1.26	-1.38		-1.26	V
V_{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 2) $V_{pp} < 500\text{ mV}$ $V_{pp} \geq 500\text{ mV}$	$V_{EE}+1.3$ $V_{EE}+1.5$		-0.4 -0.4	$V_{EE}+1.2$ $V_{EE}+1.4$		-0.4 -0.4	$V_{EE}+1.2$ $V_{EE}+1.4$		-0.4	V
I_{IH}	Input HIGH Current			150			150			150	μA
I_{IL}	Input LOW Current D \bar{D}	0.5 -600			0.5 -600			0.5 -600			μA

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Input parameters vary 1:1 with GND. V_{EE} can vary -3.0 V to -5.5 V.
2. V_{IHCMR} min varies 1:1 with V_{EE} . V_{IHCMR} max varies 1:1 with GND.

Table 4. LVPECL OUTPUT DC CHARACTERISTICS ($V_{CC}= 3.3\text{ V}$; $V_{EE}= -3.3\text{ V}$; $GND= 0\text{ V}$ (Note 1))

Symbol	Characteristic	-40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{CC}	V_{CC} Power Supply Current			24		20	24			26	mA
V_{OH}	Output HIGH Voltage (Note 2)	2215	2295	2420	2275	2345	2420	2275	2345	2420	mV
V_{OL}	Output LOW Voltage (Note 2)	1470	1605	1745	1490	1600	1680	1490	1595	1680	mV

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Output parameters vary 1:1 with V_{CC} . V_{CC} can vary +0.5 V / -0.3 V. V_{EE} can vary -3.0 V to -5.5 V.
2. Outputs are terminated through a 50 Ω resistor to $V_{CC}-2$ volts.

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Table 5. AC CHARACTERISTICS ($V_{CC} = 3.0\text{ V to }3.8\text{ V}$; $V_{EE} = -3.0\text{ V to }-5.5\text{ V}$; $GND = 0\text{ V}$)

Symbol	Characteristic	-40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
f _{max}	Maximum Toggle Frequency		560			650			700		MHz
t _{PLH} t _{PHL}	Propagation Delay Diff D to Q S.E.	390		590	420		620	460		660	ps
t _{SKEW}	Skew Output-to-Output (Note 1) Part-to-Part (Diff) (Note 1) Duty Cycle (Diff) (Note 2)		20	100		20	100		20	100	ps
t _{JITTER}	Random Clock Jitter		TBD			TBD			TBD		ps
V _{PP}	Input Voltage Swing (Differential Configuration) (Note 3)	150		1000	150		1000	150		1000	mV
t _r t _f	Output Rise/Fall Times Q (20% – 80%)	230		500	230		500	230		500	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Skews are valid across specified voltage range, part-to-part skew is for a given temperature.
2. Duty cycle skew is the difference between a TPLH and TPHL propagation delay through a device.
3. V_{PP} (min) is swing measured single-ended on each input in differential configuration. The device has a DC gain of ≈40.

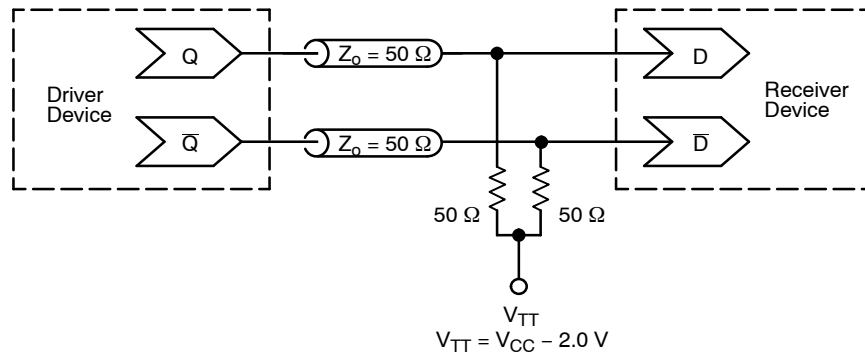


Figure 2. Typical Termination for Output Driver and Device Evaluation
(See Application Note [AND8020/D](#) – Termination of ECL Logic Devices.)

Resource Reference of Application Notes

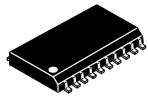
- AN1405/D** – ECL Clock Distribution Techniques
- AN1406/D** – Designing with PECL (ECL at +5.0 V)
- AN1503/D** – ECLinPS I/O SPICE Modeling Kit
- AN1504/D** – Metastability and the ECLinPS Family
- AN1568/D** – Interfacing Between LVDS and ECL
- AN1672/D** – The ECL Translator Guide
- AND8001/D** – Odd Number Counters Design
- AND8002/D** – Marking and Date Codes
- AND8020/D** – Termination of ECL Logic Devices
- AND8066/D** – Interfacing with ECLinPS
- AND8090/D** – AC Characteristics of ECL Devices

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MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

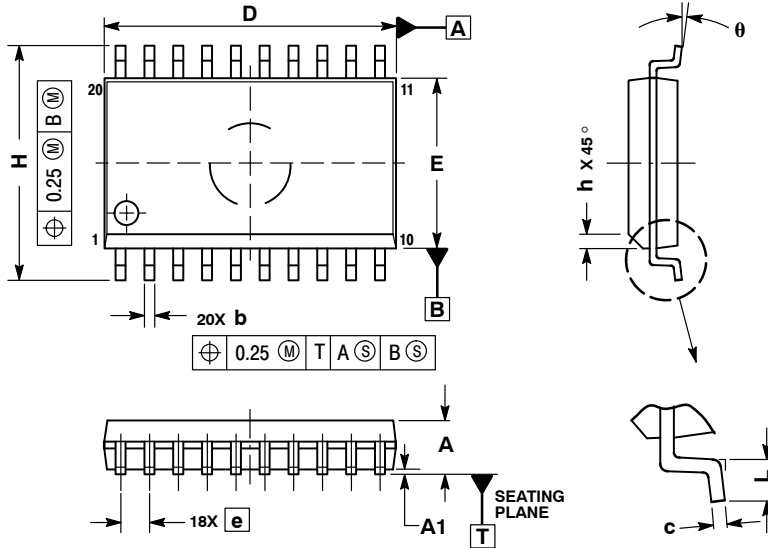
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SCALE 1:1

SOIC-20 WB
CASE 751D-05
ISSUE H

DATE 22 APR 2015

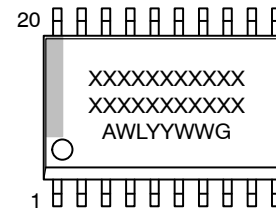


NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

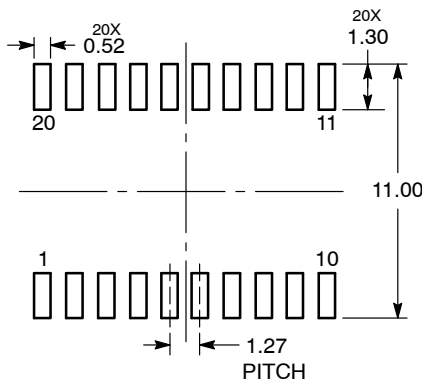
DIM	MILLIMETERS	
	MIN	MAX
A	2.35	2.65
A1	0.10	0.25
b	0.35	0.49
c	0.23	0.32
D	12.65	12.95
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.25	0.75
L	0.50	0.90
θ	0°	7°

GENERIC MARKING DIAGRAM*



- XXXXXX = Specific Device Code
- A = Assembly Location
- WL = Wafer Lot
- YY = Year
- WW = Work Week
- G = Pb-Free Package

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

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